NSN 5961-01-387-3572

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.160 inches and 0.180 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-205af

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

500.0 drain to gate voltage and 500.0 forward voltage, average and 20.0 gate to source voltage

Current Rating Per Characteristic:

11.00 amperes off-state current, peak

Power Rating Per Characteristic:

25.0 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Test Data Document:

08748-tr169 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-prf-19500/557 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.